Revision. 2

MOS FET

### FG6943010R

# **Panasonic**

## FG6943010R

Silicon N-channel MOSFET(FET1) Silicon P-channel MOSFET(FET2)

#### For switching

#### ■ Features

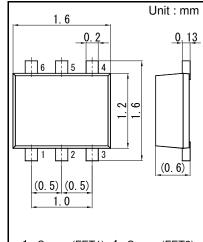
- Low drive voltage: 2.5 V drive
  Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol V7
- Basic Part Number FJ330301 + FK330301 (Individual)

#### ■ Packaging

Embossed type (Thermo-compression sealing) 8 000 pcs / reel (standard)

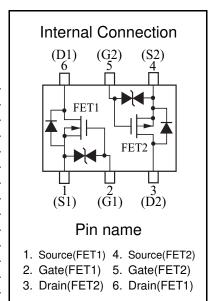
■ Absolute Maximum Ratings Ta = 25 °C

Parameter		Rating	Unit	
Drain-source voltage	VDS	30	V	
Gate-source voltage	VGS	±12	V	
Drain current	ID	100	mA	
Pulse drain current	IDp	200	mA	
Drain-source voltage	VDS	-30	V	
Gate-source voltage	VGS	±12	V	
Drain current	ID	-100	mA	
Pulse drain current	IDp	-200	mA	
Total power dissipation	PT	125	mW	
Channel temperature	Tch	150	°C	
Operating ambient temperature	Topr	-40 to + 85	°C	
Storage temperature	Tstg	-55 to +150	°C	
	Drain-source voltage Gate-source voltage Drain current Pulse drain current Drain-source voltage Gate-source voltage Gate-source voltage Drain current Pulse drain current Total power dissipation Channel temperature Operating ambient temperature	Drain-source voltage VDS Gate-source voltage VGS Drain current ID Pulse drain current IDp Drain-source voltage VDS Gate-source voltage VDS Gate-source voltage VGS Drain current ID Pulse drain current ID Pulse drain current ID Channel temperature Tch Operating ambient temperature	Drain-source voltage         VDS         30           Gate-source voltage         VGS         ±12           Drain current         ID         100           Pulse drain current         IDp         200           Drain-source voltage         VDS         -30           Gate-source voltage         VGS         ±12           Drain current         ID         -100           Pulse drain current         IDp         -200           Total power dissipation         PT         125           Channel temperature         Tch         150           Operating ambient temperature         Topr         -40 to + 85	



- 1. Source(FET1) 4. Source(FET2)
- 2. Gate(FET1) 5. Gate(FET2)
- 3. Drain(FET2) 6. Drain(FET1)

Panasonic	SSMini6-F3-B
JEITA	SC-107C
Code	SOT-666



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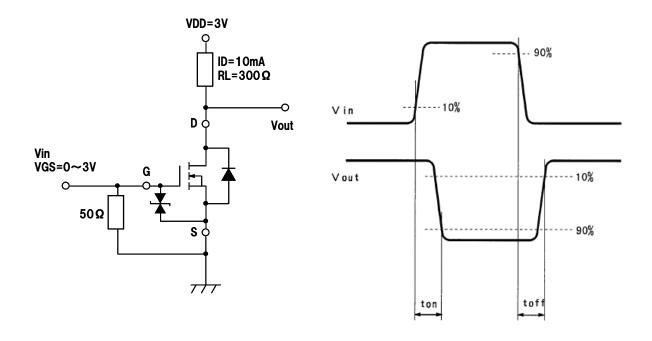
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## ■ Electrical Characteristics Ta = 25 °C ± 3 °C

FET1 Parameter Symbol Conditions Min Typ Max Unit 30 Drain-source breakdown voltage **VDSS** ID = 1 mA, VGS = 0V IDSS VDS = 30 V, VGS = 0 Drain-source cutoff current 1.0 μΑ Gate-source cutoff current **IGSS**  $VGS = \pm 10 \text{ V}, VDS = 0$ ±10 μА Gate threshold voltage VTH  $ID = 1.0 \mu A, VDS = 3.0 V$ 0.5 1.0 1.5 ٧ ID = 10 mA, VGS = 2.5 V RDS(on)1 3 6 Ω Drain-source ON resistance RDS(on)2 ID = 10 mA, VGS = 4.0 V 2 3 Ω Forward transfer admittance ID = 10 mA, VDS = 3.0 V 20 |Yfs| 55 mS Input capacitance Ciss 12 pF Coss VDS = 3 V, VGS = 0, f = 1 MHz7 Output capacitance pF Reverse transfer capacitance 3 Crss рF VDD = 3 V, VGS = 0 to 3 V 100 Turn-on time \*1 ton ns ID = 10 mAVDD = 3 V, VGS = 3 to 0 V Turn-off time \*1 toff 100 ns ID = 10 mA

1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

2. \*1 FET1 Turn-on and Turn-off test circuit



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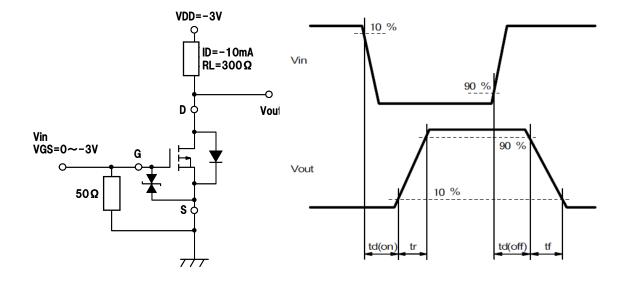
MOS FET

FG6943010R

## ■ Electrical Characteristics $Ta = 25 \, ^{\circ}C \pm 3 \, ^{\circ}C$ FET2

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source breakdown voltage	VDSS	ID = -1mA, $VGS = 0$	-30			V
Drain-source cutoff current	IDSS	VDS = -30 V, VGS = 0			-1.0	μΑ
Gate-source cutoff current	IGSS	$VGS = \pm 10 \text{ V, VDS} = 0$			±10	μΑ
Gate threshold voltage	VTH	ID = -1.0 $\mu$ A, VDS = -3.0 V	-0.5	-1.0	-1.5	V
Drain-source ON resistance	RDS(on)1	ID = -10 mA, VGS = -2.5 V		7	17	Ω
	RDS(on)2	ID = -10 mA, VGS = -4.0 V		4	7	Ω
Forward transfer admittance	Yfs	ID = -10 mA, VDS = -3.0 V	20	40		mS
Input capacitance	Ciss	VDS = -3 V, VGS = 0, f = 1 MHz		12		pF
Output capacitance	Coss			7		pF
Reverse transfer capacitance	Crss			3		pF
Turn-on time <sup>*1</sup>	ton	VDD = -3 V, $VGS = 0  to  -3 V$ , $ID = -10  mA$		100		ns
Turn-off time <sup>*1</sup>	toff	VDD = -3 V, $VGS = -3 to 0 V$ , $ID = -10 mA$		100		ns

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

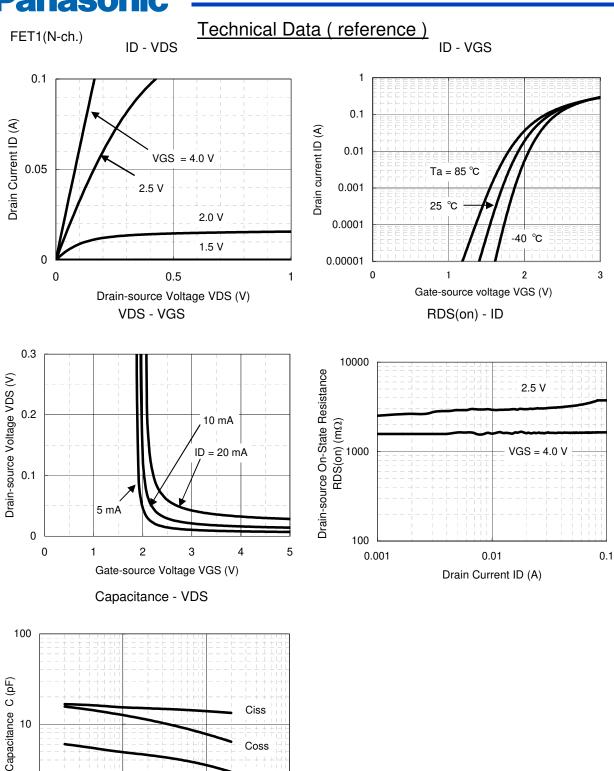


<sup>2. \*1</sup> FET2 Turn-on and Turn-off test circuit

MOS FET

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Crss

100

10

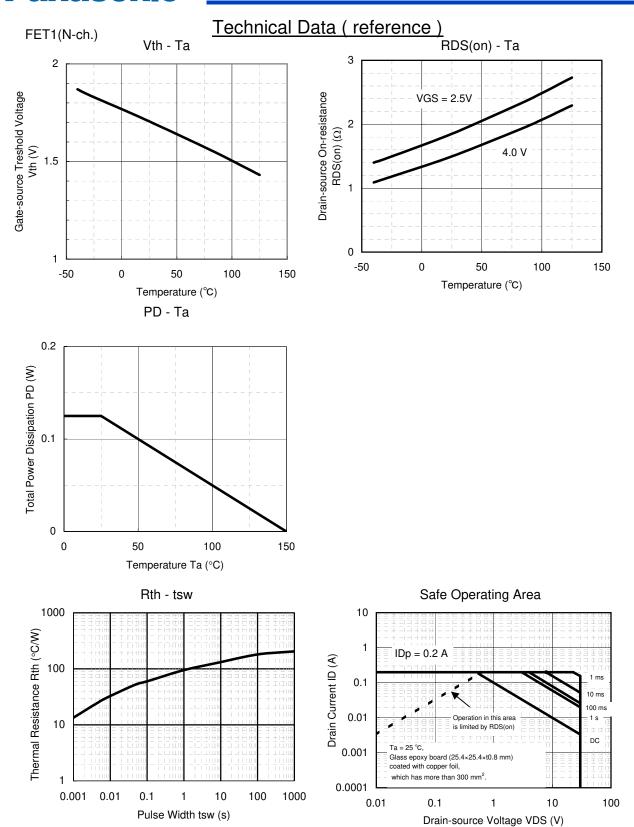
Drain-source Voltage VDS (V)

0.1

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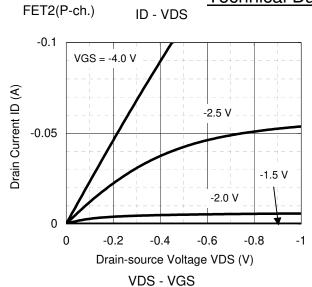


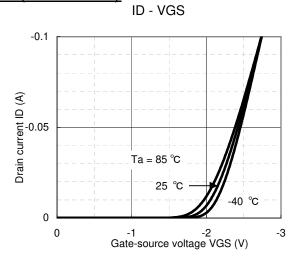
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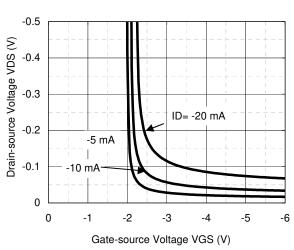
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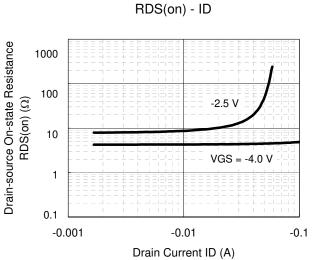
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## Technical Data (reference)

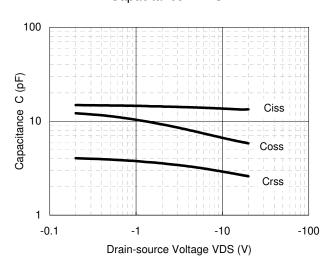








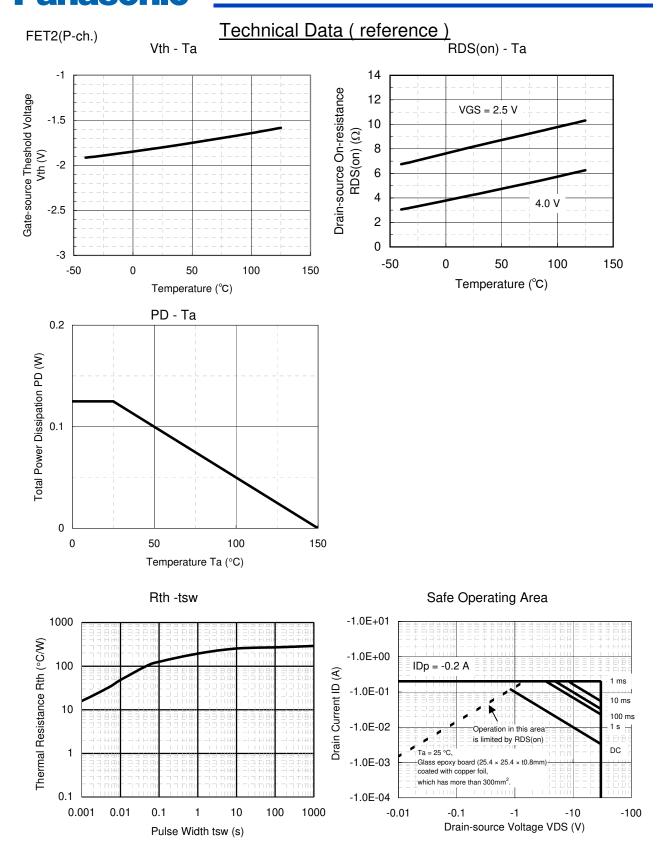
Capacitance - VDS



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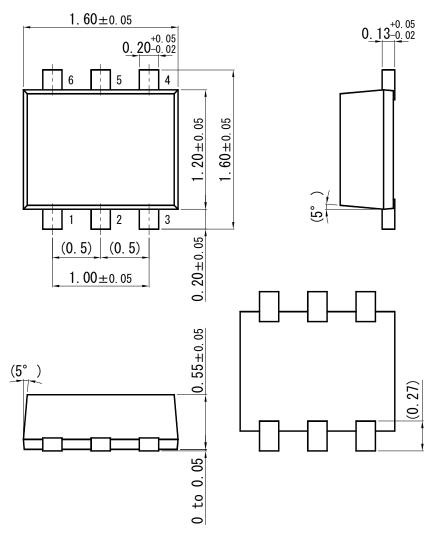


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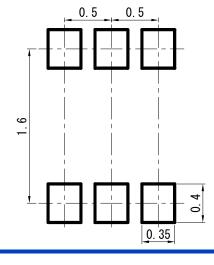
## FG6943010R

# **Panasonic** SSMini6-F3-B

Unit: mm



### ■ Land Pattern (Reference) (Unit: mm



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